Appl. No.: 10/087,146 Amdt. Dated: December 16, 2003

Reply to Office Action of: October 10, 2003

Amendments to the Specification:

Please replace the originally filed abstract with the following amended abstract:

Abstract of the Invention

The invention provides a method of making ≥ 4 kHz repetition rate argon fluoride excimer laser crystal optics. The method includes providing a solid magnesium fluoride crystal colid precursor, nonmetallically crushing the magnesium fluoride solid precursor to provide a crushed, low metal contaminant magnesium fluoride feedstock, providing a magnesium fluoride crystal growth crucible, loading the crushed magnesium fluoride feedstock into the crystal growth crucible, melting the loaded, crushed magnesium fluoride feedstock to provide a precrystalline magnesium fluoride melt, growing an oriented magnesium fluoride crystal from the precrystalline magnesium fluoride melt, cooling the grown magnesium fluoride crystal to provide a magnesium fluoride laser optical crystal having a 120 nm transmission of at least 30%, and forming the magnesium fluoride laser crystal into an excimer laser crystal optic for transmitting a high repetition rate (≥ 4 kHz repetition rate) excimer laser output.